

L Number	Hits	Search Text	DB	Time stamp
-	40517	MRAM (magnetic near4 memory)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/09/02 13:45
-	3376	((MRAM (magnetic near4 memory)) and ((magnet\$2 ferromagnet\$2) adj2 layer))	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/09/02 13:46
-	996	magnet\$2 near3 tunnel\$3 near3 junction	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/09/02 13:47
-	517	((MRAM (magnetic near4 memory)) and ((magnet\$2 ferromagnet\$2) adj2 layer)) and (magnet\$2 near3 tunnel\$3 near3 junction)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/09/02 13:47
-	10	((((MRAM (magnetic near4 memory)) and ((magnet\$2 ferromagnet\$2) adj2 layer)) and (magnet\$2 near3 tunnel\$3 near3 junction)) and ((magnet\$2 near3 tunnel\$3 near3 junction) with source) and ((magnet\$2 near3 tunnel\$3 near3 junction) with gate)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/09/02 14:02
-	0	(MRAM (magnetic near4 memory)) and ((magnet\$2 adj2 tunnel\$3) near3 source) and ((magnet\$2 adj2 tunnel\$3) near3 gate)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/09/02 14:03
-	1	(MRAM (magnetic near4 memory)) and ((magnet\$2 near3 tunnel\$3 near3 junction) near3 source) and ((magnet\$2 near3 tunnel\$3 near3 junction) near3 gate)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/09/02 14:17
-	0	(MRAM (magnetic near4 memory)) and ((junction adj3 end) near3 gate) and ((junction adj3 end) near3 source)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/09/02 14:23
-	4411	mizushima.in.	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/09/02 15:18
-	173	(mizushima near koichi).in.	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/09/02 15:19
-	26	((mizushima near koichi).in.) and magnetic	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/09/02 15:21
-	26	((mizushima near koichi).in.) and magnet\$3	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/09/02 15:21
-	16	(MRAM (magnetic near4 memory)) and ((magnet\$2 near3 tunnel\$3 near3 junction) with source) and ((magnet\$2 near3 tunnel\$3 near3 junction) with gate)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/01/15 13:22

-	47	(MRAM (magnetic near4 memory)) and ((MTJ (magnet\$2 near3 tunnel\$3 near3 junction)) with source) and ((MTJ (magnet\$2 near3 tunnel\$3 near3 junction)) with gate)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/01/15 13:19
-	4736	MTJ (magnet\$2 near3 tunnel\$3 near3 junction) TMR (tunnel\$3 near3 magnet\$2 near3 resist\$3)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/01/15 13:21
-	103	(MRAM (magnetic near4 memory)) and ((MTJ (magnet\$2 near3 tunnel\$3 near3 junction) TMR (tunnel\$3 near3 magnet\$2 near3 resist\$3)) with source) and ((MTJ (magnet\$2 near3 tunnel\$3 near3 junction) TMR (tunnel\$3 near3 magnet\$2 near3 resist\$3)) with gate)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/09/03 19:19